

BC490, BC490A

High Current Transistors

PNP Silicon

Features

- Pb-Free Packages are Available*

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector – Emitter Voltage	V_{CEO}	-80	Vdc
Collector – Base Voltage	V_{CBO}	-80	Vdc
Emitter – Base Voltage	V_{EBO}	-4.0	Vdc
Collector Current – Continuous	I_C	-1.0	Adc
Total Device Dissipation @ $T_A = 25^\circ\text{C}$ Derate above 25°C	P_D	625 5.0	mW mW/ $^\circ\text{C}$
Total Device Dissipation @ $T_C = 25^\circ\text{C}$ Derate above 25°C	P_D	1.5 12	W mW/ $^\circ\text{C}$
Operating and Storage Junction Temperature Range	T_J, T_{stg}	-55 to +150	$^\circ\text{C}$

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

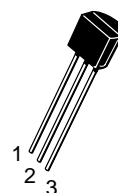
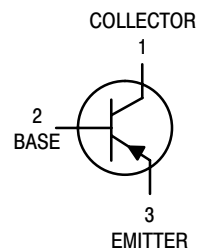
THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	200	$^\circ\text{C}/\text{W}$
Thermal Resistance, Junction-to-Case	$R_{\theta JC}$	83.3	$^\circ\text{C}/\text{W}$



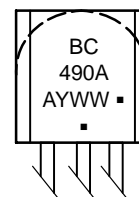
ON Semiconductor®

<http://onsemi.com>



TO-92
CASE 29
STYLE 17

MARKING DIAGRAM



BC490A = Device Code
A = Assembly Location
Y = Year
WW = Work Week
■ = Pb-Free Package

(Note: Microdot may be in either location)

ORDERING INFORMATION

Device	Package	Shipping
BC490	TO-92	5000 Units / Box
BC490G	TO-92 (Pb-Free)	5000 Units / Box
BC490A	TO-92	5000 Units / Box
BC490AG	TO-92 (Pb-Free)	5000 Units / Box
BC490AZL1	TO-92	2000 / Ammo Box
BC490AZL1G	TO-92 (Pb-Free)	2000 / Ammo Box

*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

Characteristic	Symbol	Min	Typ	Max	Unit
OFF CHARACTERISTICS					
Collector–Emitter Breakdown Voltage (Note 1) (I _C = –10 mA _{dc} , I _B = 0)	V _{(BR)CEO}	–80	–	–	V _{dc}
Collector–Base Breakdown Voltage (I _C = –100 μA _{dc} , I _E = 0)	V _{(BR)CBO}	–80	–	–	V _{dc}
Emitter–Base Breakdown Voltage (I _E = –10 μA _{dc} , I _C = 0)	V _{(BR)EBO}	–4.0	–	–	V _{dc}
Collector Cutoff Current (V _{CB} = –60 V _{dc} , I _E = 0)	I _{CBO}	–	–	–100	nA _{dc}

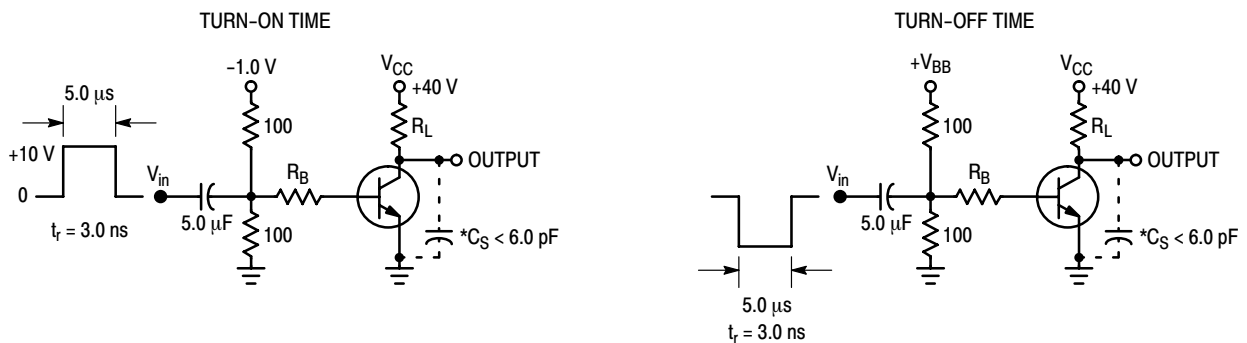
ON CHARACTERISTICS

DC Current Gain (I _C = –10 mA _{dc} , V _{CE} = –2.0 V _{dc}) (I _C = –100 mA _{dc} , V _{CE} = –2.0 V _{dc}) (I _C = –1.0 A _{dc} , V _{CE} = –5.0 V _{dc})	h _{FE} BC490 BC490A	40 60 100 15	– – 140 –	– – 250 –	–
Collector–Emitter Saturation Voltage (I _C = –500 mA _{dc} , I _B = –50 mA _{dc}) (I _C = –1.0 A _{dc} , I _B = –100 mA _{dc})	V _{CE(sat)}	– –	–0.25 –0.5	–0.5 –	V _{dc}
Base–Emitter Saturation Voltage (I _C = –500 mA _{dc} , I _B = –50 mA _{dc}) (I _C = –1.0 A _{dc} , I _B = –100 mA _{dc})	V _{BE(sat)}	– –	–0.9 –1.0	–1.2 –	V _{dc}

DYNAMIC CHARACTERISTICS

Current–Gain – Bandwidth Product (I _C = –50 mA _{dc} , V _{CE} = –2.0 V _{dc} , f = 100 MHz)	f _T	–	150	–	MHz
Output Capacitance (V _{CB} = –10 V _{dc} , I _E = 0, f = 1.0 MHz)	C _{ob}	–	9.0	–	pF
Input Capacitance (V _{EB} = –0.5 V _{dc} , I _C = 0, f = 1.0 MHz)	C _{ib}	–	110	–	pF

1. Pulse Test: Pulse Width = 300 μs, Duty Cycle 2%.



*Total Shunt Capacitance of Test Jig and Connectors
For PNP Test Circuits, Reverse All Voltage Polarities

Figure 1. Switching Time Test Circuits

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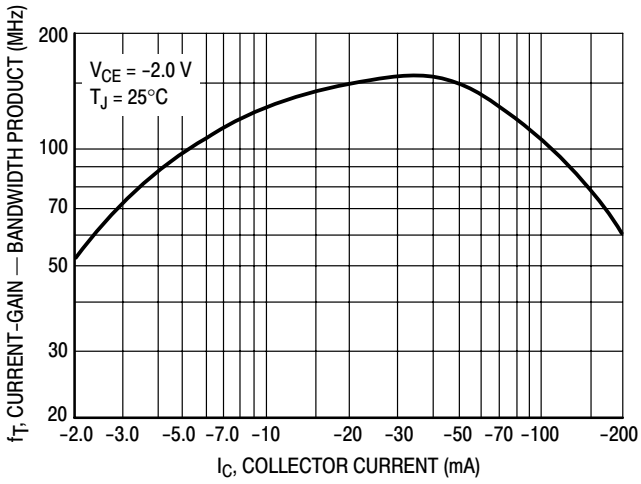


Figure 2. Current-Gain — Bandwidth Product

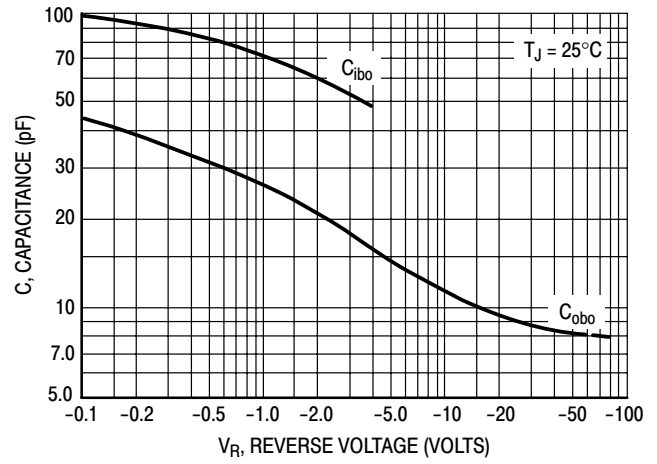


Figure 3. Capacitance

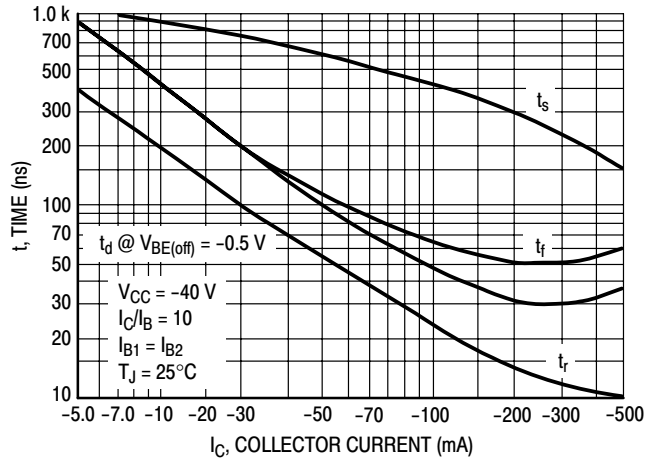


Figure 4. Switching Time

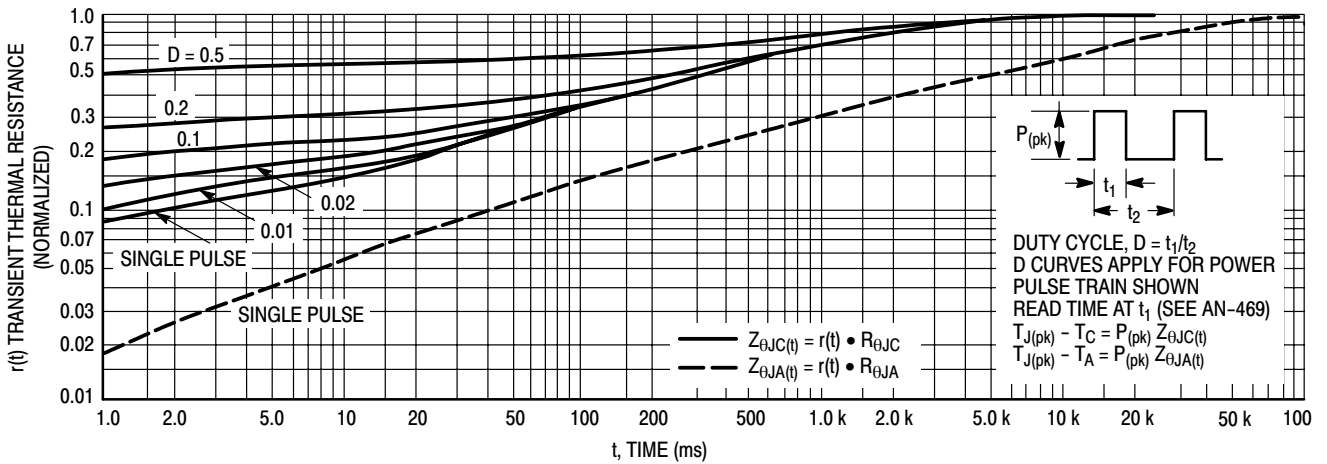


Figure 5. Thermal Response

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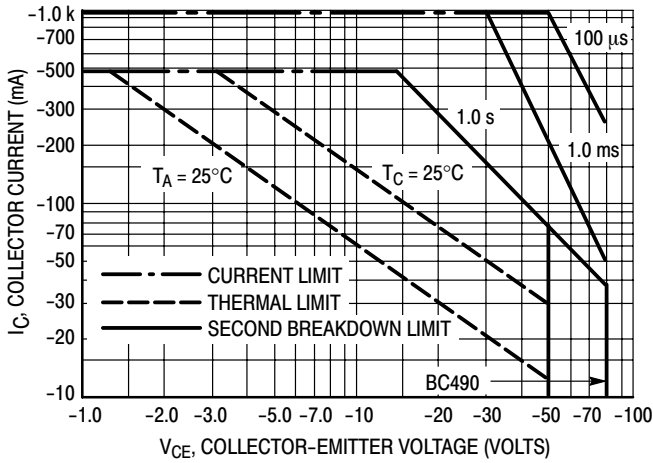


Figure 6. Active Region, Safe Operating Area

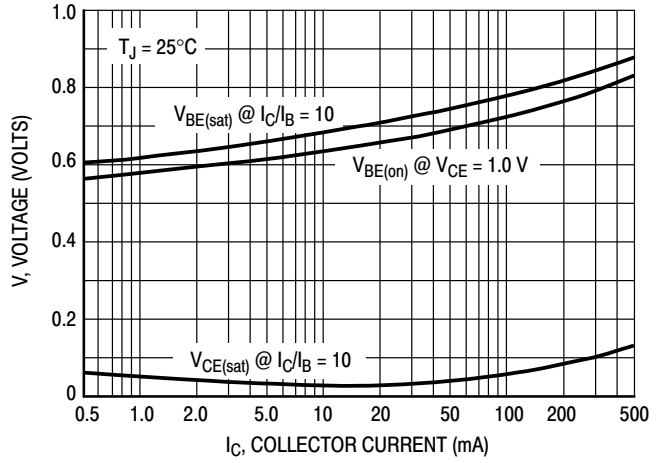


Figure 7. "On" Voltages

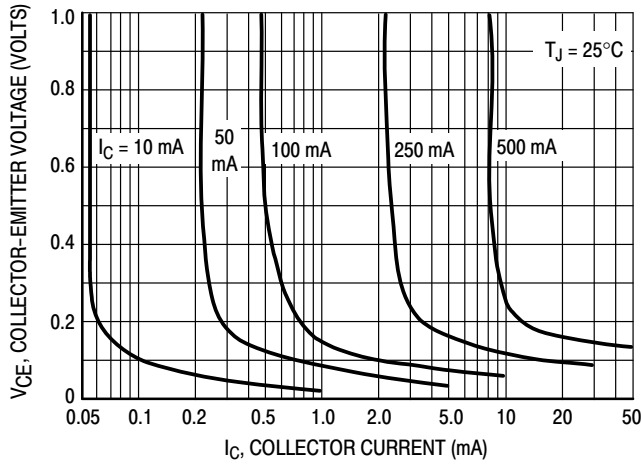


Figure 8. Collector Saturation Region

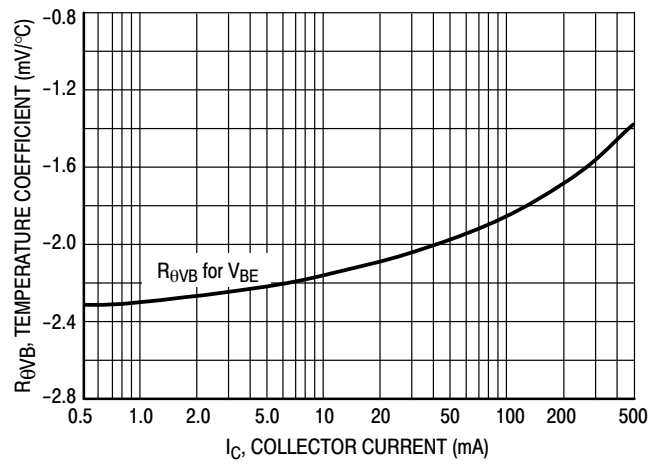


Figure 9. Base-Emitter Temperature Coefficient

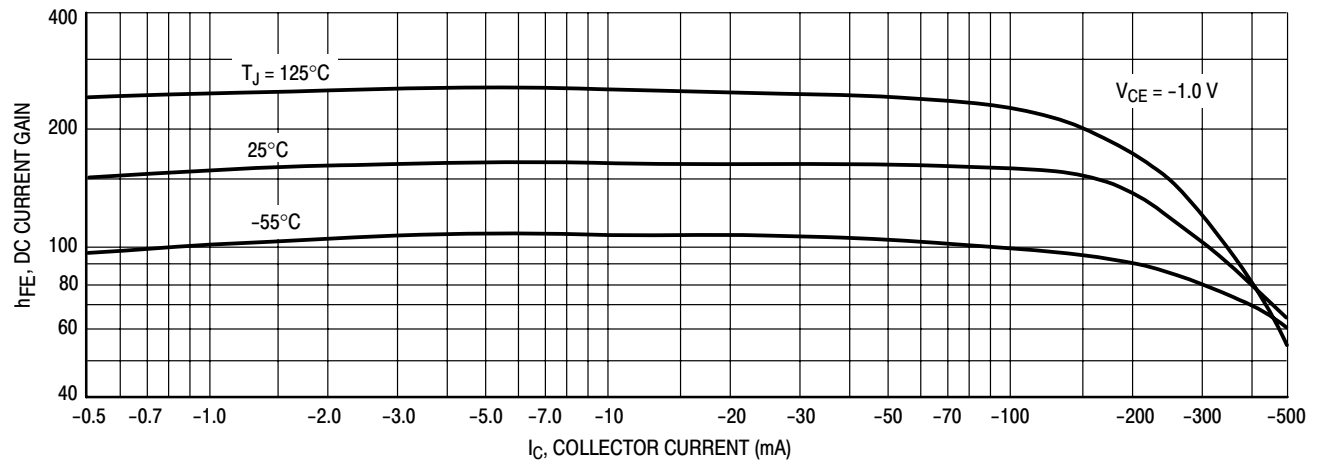


Figure 10. DC Current Gain

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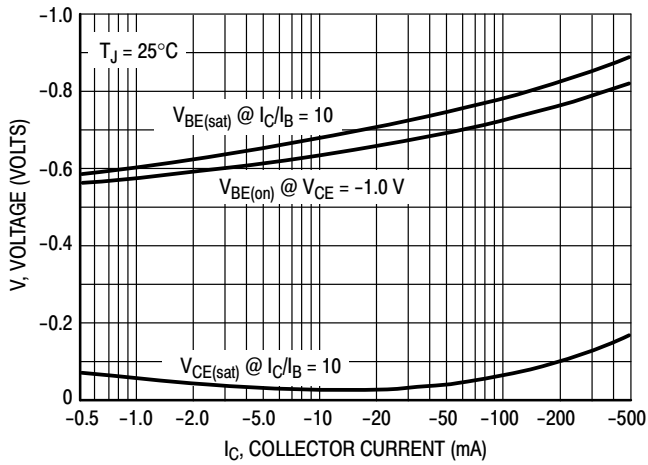


Figure 11. "On" Voltages

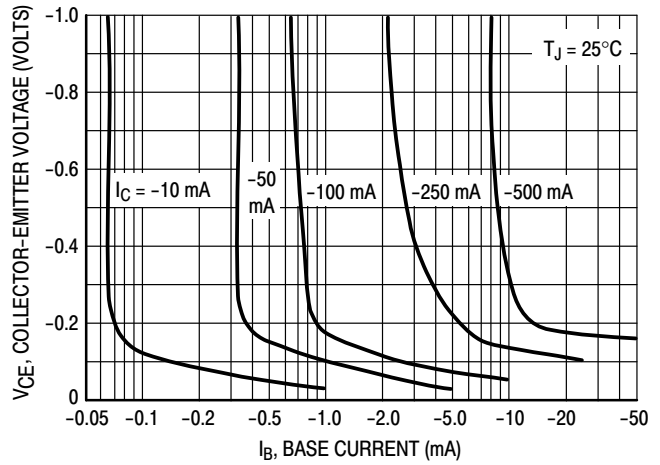


Figure 12. Collector Saturation Region

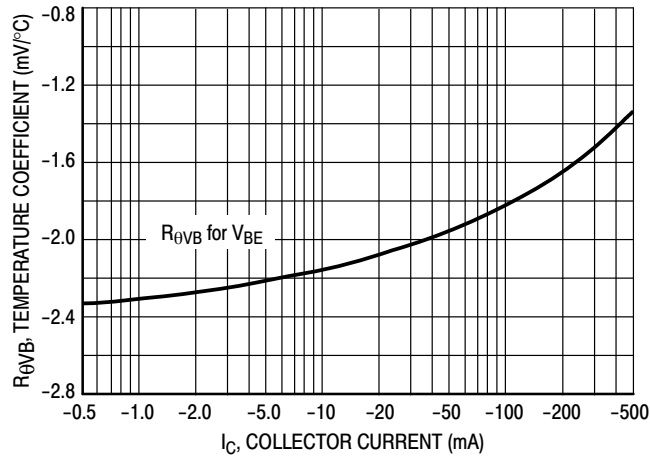
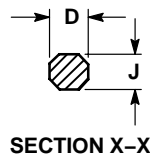
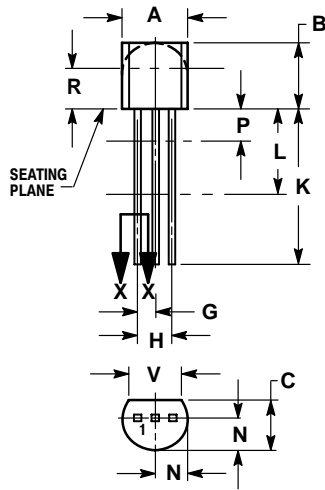


Figure 13. Base-Emitter Temperature Coefficient

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PACKAGE DIMENSIONS

TO-92
(TO-226)
CASE 29-11
ISSUE AL



NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.
3. CONTOUR OF PACKAGE BEYOND DIMENSION R IS UNCONTROLLED.
4. LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.175	0.205	4.45	5.20
B	0.170	0.210	4.32	5.33
C	0.125	0.165	3.18	4.19
D	0.016	0.021	0.407	0.533
G	0.045	0.055	1.15	1.39
H	0.095	0.105	2.42	2.66
J	0.015	0.020	0.39	0.50
K	0.500	---	12.70	---
L	0.250	---	6.35	---
N	0.080	0.105	2.04	2.66
P	---	0.100	---	2.54
R	0.115	---	2.93	---
V	0.135	---	3.43	---

STYLE 17:

1. COLLECTOR
2. BASE
3. EMITTER

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